HIR.201

10/567369 IAP9 Rec'd PCTVPTO 07 FEB 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Noboru ICHINOSE, et al.

Serial No.:

Not Yet Assigned

Group Art Unit:

Not Yet Assigned

Filing Date:

Concurrently Herewith

Examiner:

Not Yet Assigned

For:

SEMICONDUCTOR LAYER

Honorable Commissioner of Patents Alexandria, Virginia 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.98 and pursuant to applicants' duty of disclosure under 37 CFR §1.56, applicants respectfully bring the following documents listed on the attached form PTO-1449 and cited in the International Search Report (PCT Form PCT/ISA/210) and International Preliminary Examination Report in a counterpart foreign application, to the attention of the Examiner in charge of the above-identified application. Copies of the listed documents are provided herewith for the convenience of the Examiner. Further, in compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, English-language Abstracts are attached to the references.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which applicants are aware.

It is respectfully requested that the listed references be considered by the Examiner and formally made of record in this application.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

Date:

MCGINN INTELLECTUAL PROPERTY

LAW GROUP, PLLC

8321 Old Courthouse Road, Suite 200

Vienna, Virginia 22182-3817

(703) 761-4100, Customer No. 21254

Respectfully submitted,

Sean M. McGinn, Esq. Registration No.: 34,386

INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)

PKHF-04053US

Applicant(s) Noboru ICHIN

Filing Date

Group Art Unit

Not Vet Assigned

	•		<u>, </u>			Concurrently Her	CWILLI	1101 16	Assigned	
				U.S.	. PATENT I	OCUMENTS				
*EXAMINER INITIAL	REF		DOCUMENT NUMBER	DATE		NAME	CLASS	SUBCLASS	FILING IF APPRO	
			<i>"</i>							
-										
				U.S. PATENT	T APPLICA	ΓΙΟΝ PUBLICATIONS	_			
*EXAMINER INITIAL	REF	REF DOCUMENT NUMBER		DATE	NAME		CLASS	SUBCLASS	FILING DATE IF APPROPRIATE	
	,									
				FORE	IGN PATEN	T DOCUMENTS	_			
	REF	DOCUMENT NUMBER		DATE		COUNTRY	CLASS	SUBCLASS	Trans YES	lation NO
	·	2003	3-46128	02/14/2003	JAPAN				ABS	
		2000-349336		12/15/2000	JAPAN				ABS	
									ļ	
-								<u> </u>		
				OTHER I	DOCUMEN'	rs (Including Autho	r, Title, Date, Pe	rtinent Pages, E	itc.)	
Yang, Ying-Ge, "Preparation and Structural Properties for GaN Films Grown on Si (1 1 1) by Annealing", Applied Surface Science, Vol. 193, 2002, pages 254 -260										
	:									
EXAMINER						DATE CONSIDERED				
			itation considered, whether copy of this form with nex			ce with MPEP Section 609;	Draw line throu	gh citation if no	ot in conform	ance and